

## **isc Silicon PNP Power Transistor**

## **BD738**

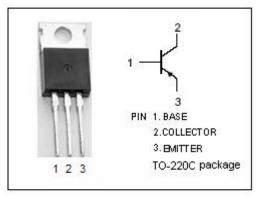
### DESCRIPTION

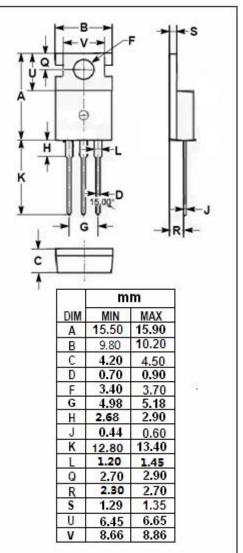
- DC Current Gain -
  - : h<sub>FE</sub> = 40(Min.)@ I<sub>C</sub>= -20mA
- Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -45V(Min.)
- Complement to Type BD737
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **APPLICATIONS**

· Designed for amplifier and switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)						
SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>CBO</sub>	Collector-Base Voltage	-45	V			
V <sub>CEO</sub>	Collector-Emitter Voltage	-45	V			
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V			
Ic	Collector Current-Continuous	-4	А			
I <sub>CM</sub>	Collector Current-Peak	-7	A			
I <sub>B</sub>	Base Current-Continuous	-1	A			
Pc	Collector Power Dissipation @ Ta=25°C	2	W			
	Collector Power Dissipation @ $T_c=25^{\circ}C$	40				
TJ	Junction Temperature	150	°C			
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C			
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isc website: www.iscsemi.com



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#### **ELECTRICAL CHARACTERISTICS**

#### Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -30mA; I <sub>B</sub> = 0	-45		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = -0.1mA; I <sub>E</sub> = 0	-45		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -1mA; I <sub>C</sub> = 0	-5		V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -2A; I <sub>B</sub> = -0.2A		-0.6	V
$V_{\text{BE(on)}}$	Base-Emitter On Voltage	I <sub>C</sub> = -2A; V <sub>CE</sub> = -1V		-1.1	V
Ices	Collector Cutoff Current	V <sub>CE</sub> = -45V; V <sub>BE</sub> = 0		-0.2	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -20mA; V <sub>CE</sub> = -4V	40		
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -2A; V <sub>CE</sub> = -1V	40		

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